Low-ohmic single-pole double-throw analog switch Rev. 1.1 — 1 August 2024 Product dat

Product data sheet

1. General description

The XS3A1T5157 is a low-ohmic single-pole double-throw analog switch suitable for use as an analog or digital 2:1 multiplexer/demultiplexer. It has a digital select input (S), two independent inputs/outputs (Y1 and Y2) and a common input/output (Z).

Schmitt trigger action at the digital input makes the circuit tolerant to slower input rise and fall times. Low threshold digital input allows this device to be driven by 1.8 V logic levels in 3.3 V applications without significant increase in supply current I_{CC}. This makes it possible for the XS3A1T5157 to switch 4.3 V signals with a 1.8 V digital controller, eliminating the need for logic level translation. The XS3A1T5157 allows signals with amplitude up to V_{CC} to be transmitted from Z to Y1 or Y2, or from Y1 or Y2 to Z. Its low ON resistance (0.5 Ω) and flatness (0.13 Ω) ensures minimal attenuation and distortion of transmitted signals.

2. Features and benefits

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
 - 1.6 Ω (typical) at V_{CC} = 1.4 V
 - 1.0 Ω (typical) at V_{CC} = 1.65 V
 - 0.55 Ω (typical) at V_{CC} = 2.3 V
 - 0.50 Ω (typical) at V_{CC} = 2.7 V
- 0.50 Ω (typical) at V_{CC} = 4.3 V
- Break-before-make switching
- High noise immunity
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD78 Class II Level A
- Low-switching threshold levels
- · Control input accepts voltages above supply voltage
- Very low supply current, even when input is below V_{CC}
- High current handling capability (350 mA continuous current under 3.3 V supply)
- ESD protection:
 - HBM ANSI/ESDA/JEDEC JS-001 class 3B exceeds 8000 V
 - CDM ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
 - IEC61000-4-2 contact discharge exceeds 8000 V for switch ports
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

nexperia

Version SOT886

SOT1202

Low-ohmic single-pole double-throw analog switch

3. Applications

- Mobile phone
- Tablet / Notebook
- Wearables

4. Ordering information

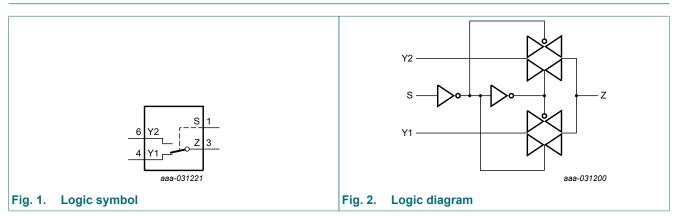
Table 1. Ordering information								
Type number	Package							
	Temperature range	Name	Description					
<u>XS3A1T5157GM</u>	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm					
<u>XS3A1T5157GS</u>	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm					

5. Marking

Table 2. Marking codes	
Type number	Marking code[1]
XS3A1T5157GM	aS
XS3A1T5157GS	aS

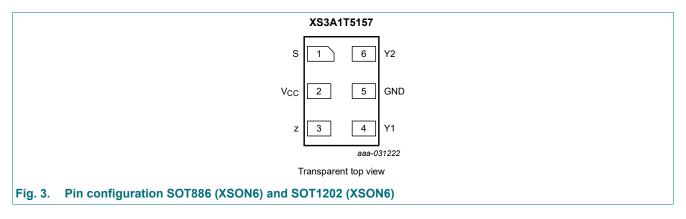
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

6. Functional diagram



7. Pinning information

7.1. Pinning



7.2. Pin description

Table 3. Pin description						
Symbol	Pin	Description				
S	1	select input				
V _{CC}	2	supply voltage				
Z	3	common input or output				
Y1	4	independent input or output				
GND	5	ground (0 V)				
Y2	6	independent input or output				

8. Functional description

Table 4. Function table

H = *HIGH* voltage level; *L* = *LOW* voltage level.

Input S	Channel on
L	Y1
Н	Y2

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+4.6	V
VI	input voltage	select input S	[1]	-0.5	+4.6	V
V _{SW}	switch voltage		[2]	-0.5	V _{CC} + 0.5	V
I _{IK}	input clamping current	V _I < -0.5 V		-50	-	mA
I _{SK}	switch clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V		-	±50	mA
I _{SW}	switch current	V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; source or sink current		-	±350	mA
		V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current		-	±500	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[3]	-	250	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] For SOT886 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C. For SOT1202 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		1.4	4.3	V
VI	input voltage	select input S	0	4.3	V
V _{SW}	switch voltage	[1]	0	V _{CC}	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 1.4 V to 4.3 V [2]	-	200	ns/V

[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Yn. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

11. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	T _{ar}	_{nb} = 25	5 °C	T _{amb} = to +8	= -40 °C 85 °C	T _{amb} = to +1	Unit	
			Min	Тур	Max	Min	Max	Min	Max	
VIH	HIGH-level	V _{CC} = 1.4 V to 1.6 V	0.9	-	-	0.9	-	0.9	-	V
	input voltage	V _{CC} = 1.65 V to 1.95 V	0.9	-	-	0.9	-	0.9	-	V
		V _{CC} = 2.3 V to 2.7 V	1.1	-	-	1.1	-	1.1	-	V
		V _{CC} = 2.7 V to 3.6 V	1.3	-	-	1.3	-	1.3	-	V
		V _{CC} = 3.6 V to 4.3 V	1.4	-	-	1.4	-	1.4	-	V
V _{IL}	LOW-level	V _{CC} = 1.4 V to 1.6 V	-	-	0.3	-	0.3	-	0.3	V
	input voltage	V _{CC} = 1.65 V to 1.95 V	-	-	0.4	-	0.4	-	0.3	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.4	-	0.4	-	0.4	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.5	-	0.5	-	0.5	V
		V _{CC} = 3.6 V to 4.3 V	-	-	0.6	-	0.6	-	0.6	V
lı	input leakage current	select input S; V _I = GND to 4.3 V; V _{CC} = 1.4 V to 4.3 V	-	-	-	-	±0.5	-	±1	μA
I _{S(OFF)}	OFF-state	Y1 and Y2 port; see Fig. 4								
. ,	/ leakage current	V _{CC} = 1.4 V to 3.6 V	-	-	±5	-	±50	-	±500	nA
		V _{CC} = 3.6 V to 4.3 V	-	-	±10	-	±50	-	±500	nA
I _{S(ON)}	ON-state leakage current	Z port; see <u>Fig. 5</u>								
. ,		V _{CC} = 1.4 V to 3.6 V	-	-	±5	-	±50	-	±500	nA
		V _{CC} = 3.6 V to 4.3 V	-	-	±10	-	±50	-	±500	nA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{SW} = GND$ or V_{CC}								
		V _{CC} = 3.6 V	-	-	100	-	690	-	6000	nA
		V _{CC} = 4.3 V	-	-	150	-	800	-	7000	nA
ΔI _{CC}	additional	V _{SW} = GND or V _{CC}								
	supply current	V _I = 2.6 V; V _{CC} = 4.3 V	-	2.0	4.0	-	7	-	7	μA
		V _I = 2.6 V; V _{CC} = 3.6 V	-	0.35	0.7	-	1	-	1	μA
		V _I = 1.8 V; V _{CC} = 4.3 V	-	7.0	10.0	-	15	-	15	μA
		V _I = 1.8 V; V _{CC} = 3.6 V	-	2.5	4.0	-	5	-	5	μA
		V _I = 1.8 V; V _{CC} = 2.5 V	-	50	200	-	300	-	500	nA
CI	input capacitance		-	1.0	-	-	-	-	-	pF
$C_{S(OFF)}$	OFF-state capacitance		-	35	-	-	-	-	-	pF
C _{S(ON)}	ON-state capacitance		-	130	-	-	-	-	-	pF

Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Fig. 7 to Fig. 13.

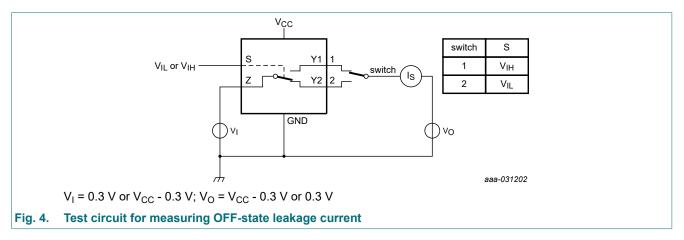
Symbol	Parameter	Conditions	T _{amb} =	-40 °C to	+85 °C	T _{amb} = -40 °	C to +125 °C	Unit
			Min	Typ[1]	Мах	Min	Max	1
R _{ON(peak)}	ON resistance (peak)	V_{I} = GND to V_{CC} ; I_{SW} = 100 mA; see <u>Fig. 6</u>						
		V _{CC} = 1.4 V	-	1.6	3.7	-	4.1	Ω
		V _{CC} = 1.65 V	-	1.0	1.6	-	1.7	Ω
		V _{CC} = 2.3 V	-	0.55	0.8	-	0.9	Ω
		V _{CC} = 2.7 V	-	0.5	0.75	-	0.9	Ω
		V _{CC} = 4.3 V	-	0.5	0.75	-	0.9	Ω
ΔR _{ON}	ON resistance mismatch	$V_{I} = GND \text{ to } V_{CC}; \qquad [2]$ $I_{SW} = 100 \text{ mA}$						
	between channels	V _{CC} = 1.4 V	-	0.04	0.3	-	0.3	Ω
	onanneis	V _{CC} = 1.65 V	-	0.04	0.2	-	0.3 0.3	Ω
		V _{CC} = 2.3 V	-	0.02	0.08	-	0.1	Ω
		V _{CC} = 2.7 V	-	0.02	0.075	-	0.1	Ω
		V _{CC} = 4.3 V	-	0.02	0.075	-	0.1	Ω
R _{ON(flat)}	ON resistance (flatness)	$V_I = GND \text{ to } V_{CC};$ [3] $I_{SW} = 100 \text{ mA}$						
		V _{CC} = 1.4 V	-	1.0	3.3	-	3.6	Ω
		V _{CC} = 1.65 V	-	0.5	1.2	-	1.3	Ω
		V _{CC} = 2.3 V	-	0.15	0.3	-	0.35	Ω
		V _{CC} = 2.7 V	-	0.13	0.3	-	0.35	Ω
		V _{CC} = 4.3 V	-	0.2	0.4	-	0.45	Ω

[1] Typical values are measured at T_{amb} = 25 °C.

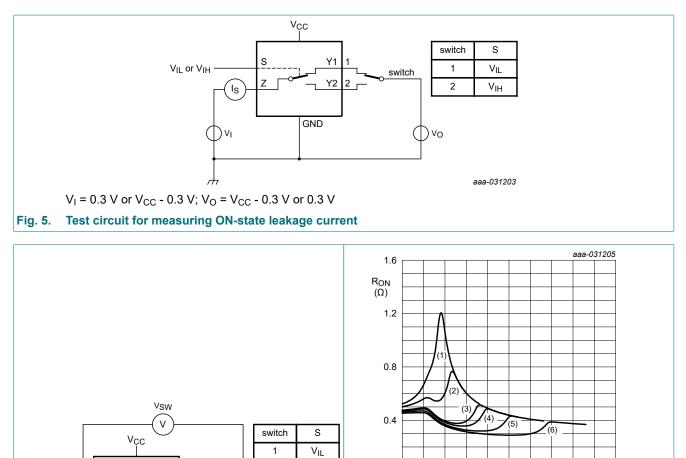
[2] Measured at identical V_{CC}, temperature and input voltage.

[3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V_{CC} and temperature.

11.1. Test circuits and graphs



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2

)∫isw

 V_{IH}

aaa-031204

0

0

1

(1) V_{CC} = 1.5 V (2) V_{CC} = 1.8 V

(3) V_{CC} = 2.5 V

(4) V_{CC} = 2.7 V (5) V_{CC} = 3.3 V

(6) V_{CC} = 4.3 V

Measured at T_{amb} = 25 °C

Fig. 7. Typical ON resistance as a function of input

2

3

4

5 V_I (V)

s

 $R_{ON} = V_{SW} / I_{SW}$

 (D_{i})

 $V_{\text{IL}} \text{ or } V_{\text{IH}}$

Fig. 6.

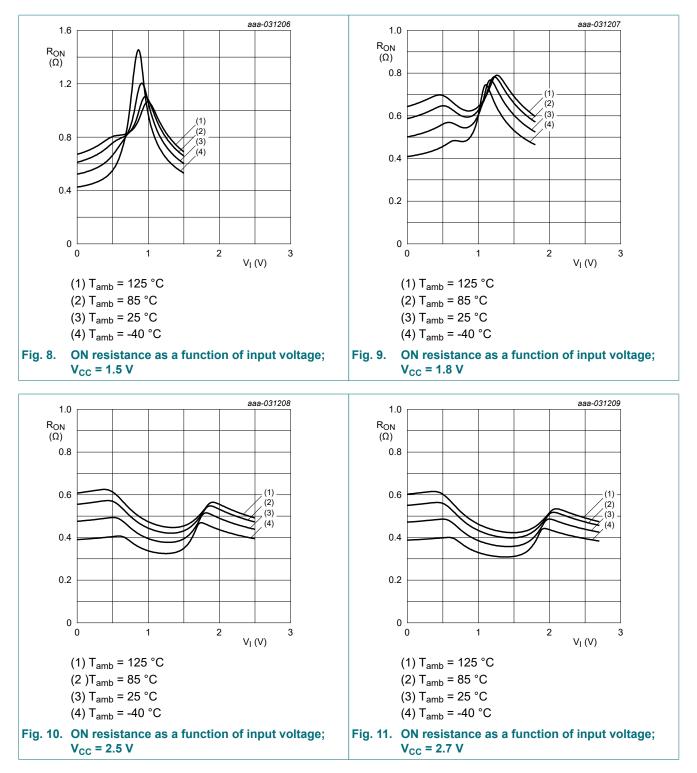
Y1

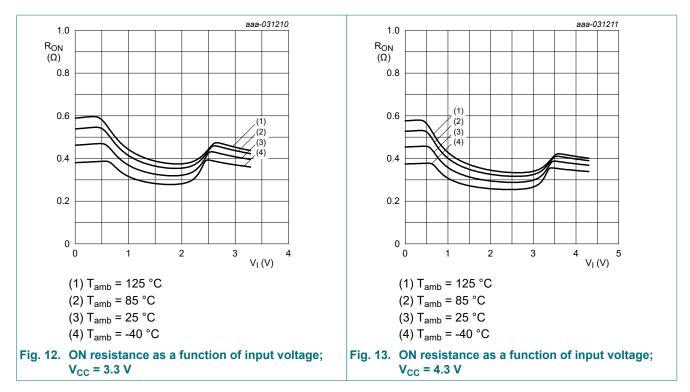
Y2

Test circuit for measuring ON resistance

GND

switch





12. Dynamic characteristics

Table 9. Dynamic characteristics

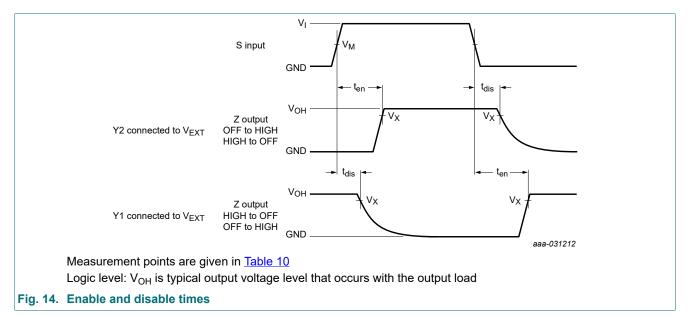
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 16.

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to	o +125 ℃	Unit
			Min	Тур [1]	Max	Min	Max	Min	Max	
t _{en}	enable time	S to Z or Yn; see Fig. 14								
		V _{CC} = 1.4 V to 1.6 V	-	50	100	-	120	-	120	ns
		V _{CC} = 1.65 V to 1.95 V	-	36	70	-	80	-	90	ns
		V _{CC} = 2.3 V to 2.7 V	-	24	45	-	50	-	55	ns
		V _{CC} = 2.7 V to 3.6 V	-	22	40	-	45	-	50	ns
		V _{CC} = 3.6 V to 4.3 V	-	22	40	-	45	-	50	ns
t _{dis}	disable time	S to Z or Yn; see Fig. 14								
		V _{CC} = 1.4 V to 1.6 V	-	32	80	-	80	-	90	ns
		V _{CC} = 1.65 V to 1.95 V	-	20	55	-	60	-	65	ns
		V _{CC} = 2.3 V to 2.7 V	-	12	25	-	30	-	35	ns
		V _{CC} = 2.7 V to 3.6 V	-	10	20	-	25	-	30	ns
		V _{CC} = 3.6 V to 4.3 V	-	10	20	-	25	-	30	ns
t _{b-m}	break-before-	see <u>Fig. 15</u> [2]								
	make time	V _{CC} = 1.4 V to 1.6 V	-	19	-	9	-	9	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	17	-	7	-	7	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	13	-	4	-	4	-	ns
		V _{CC} = 2.7 V to 3.6 V	-	10	-	3	-	3	-	ns
		V _{CC} = 3.6 V to 4.3 V	-	10	-	2	-	2	-	ns

[1] Typical values are measured at V_{CC} = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

[2] Break-before-make guaranteed by design.

XS3A1T5157



12.1. Waveform and test circuits

 Table 10. Measurement points

Supply voltage	Input	Output
V _{cc}	V _M	V _X
1.4 V to 4.3 V	0.5V _{CC}	0.9V _{OH}

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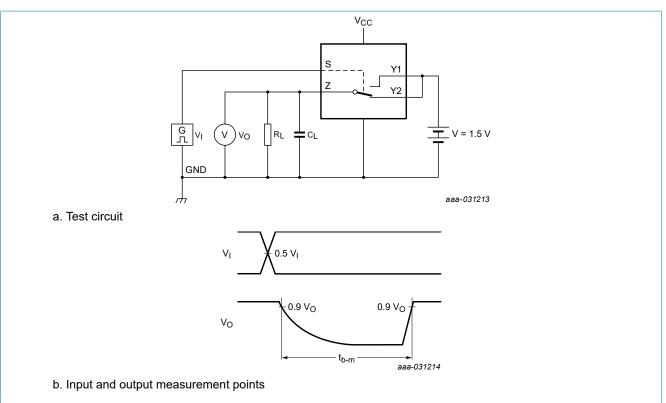


Fig. 15. Test circuit for measuring break-before-make timing

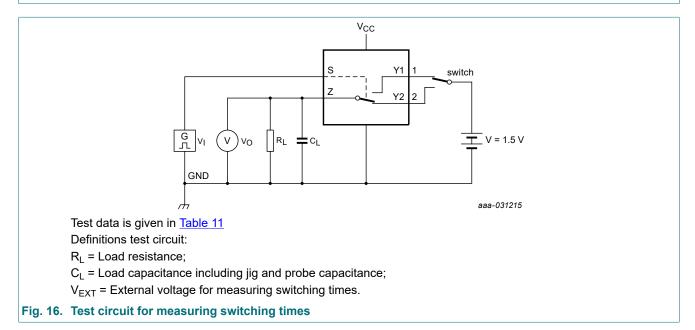


Table 11. Test data

Supply voltage	Input		Load	
V _{cc}	VI	t _r , t _f	CL	RL
1.4 V to 4.3 V	V _{CC}	≤ 2.5 ns	35 pF	50 Ω

12.2. Additional dynamic characteristics

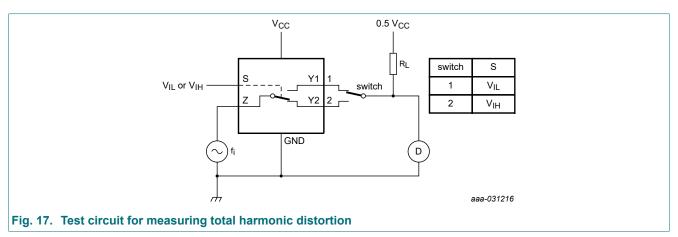
Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_I = GND$ or V_{CC} (unless otherwise specified); $t_r = t_f \le 2.5$ ns; $T_{amb} = 25$ °C.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
THD	total harmonic	f_i = 20 Hz to 20 kHz; R_L = 32 Ω ; see Fig. 17	[1]				
	distortion	V _{CC} = 1.4 V; V _I = 1 V (p-p)		-	0.15	-	%
		V _{CC} = 1.65 V; V _I = 1.2 V (p-p)		-	0.10	-	%
		V _{CC} = 2.3 V; V _I = 1.5 V (p-p)		-	0.04	- - -	%
		V _{CC} = 2.7 V; V _I = 2 V (p-p)		-	0.03	-	%
		V _{CC} = 4.3 V; V _I = 2 V (p-p)		-	0.01	-	%
f _(-3dB)	-3 dB frequency	R _L = 50 Ω; see <u>Fig. 18</u>	[1]				
	response	V _{CC} = 1.4 V to 4.3 V		-	40	-	MHz
α _{iso}	isolation (OFF-state)	f_i = 100 kHz; R _L = 50 Ω; see <u>Fig. 19</u>	[1]				
		V _{CC} = 1.4 V to 4.3 V		-	-90	-	dB
V _{ct}	crosstalk voltage	between digital inputs and switch; $f_i = 1 \text{ MHz}$; C _L = 50 pF; R _L = 50 Ω ; see <u>Fig. 20</u>	[1]				
		V _{CC} = 1.4 V to 3.6 V		-	0.4	-	V
		V _{CC} = 3.6 V to 4.3 V		-	0.6	-	V
Q _{inj}	charge injection	$ f_i = 1 \text{ MHz}; \text{C}_L = 0.1 \text{ nF}; \text{R}_L = 1 \text{M}\Omega; \text{V}_{\text{gen}} = 0 \text{V}; \\ \text{R}_{\text{gen}} = 0 \Omega; \text{ see } \overline{\text{Fig. 21}} $	[1]				
		V _{CC} = 1.5 V		-	3	-	рС
		V _{CC} = 1.8 V		-	4	-	рС
		V _{CC} = 2.5 V		-	6	-	рС
		V _{CC} = 3.3 V		-	9	-	рС
		$V_{CC} = 4.3 V$		-	15	-	рС

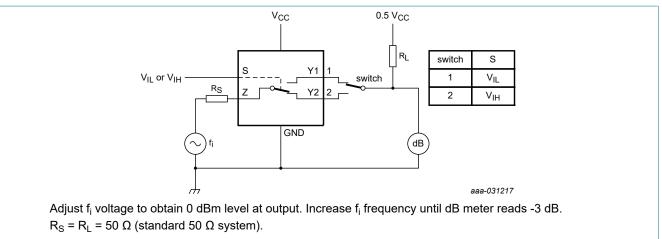
[1] f_i is biased at 0.5V_{CC}.

12.3. Test circuits

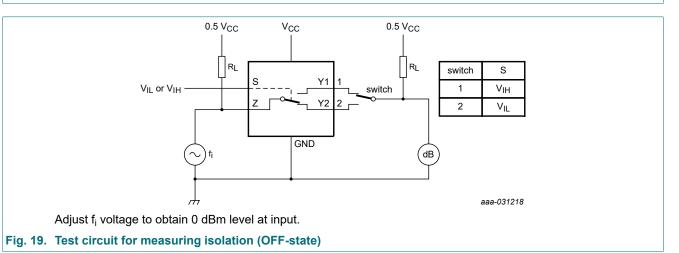


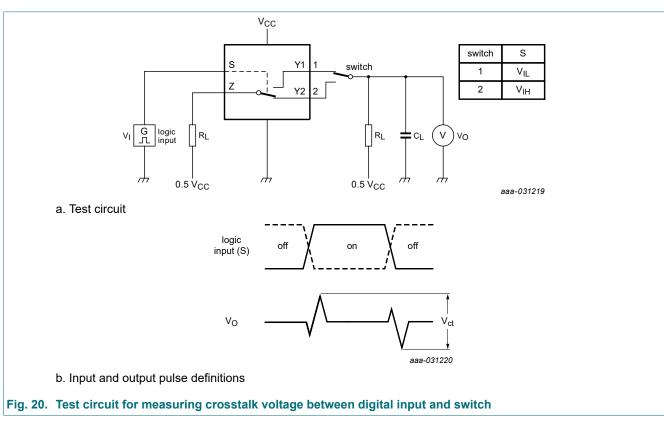
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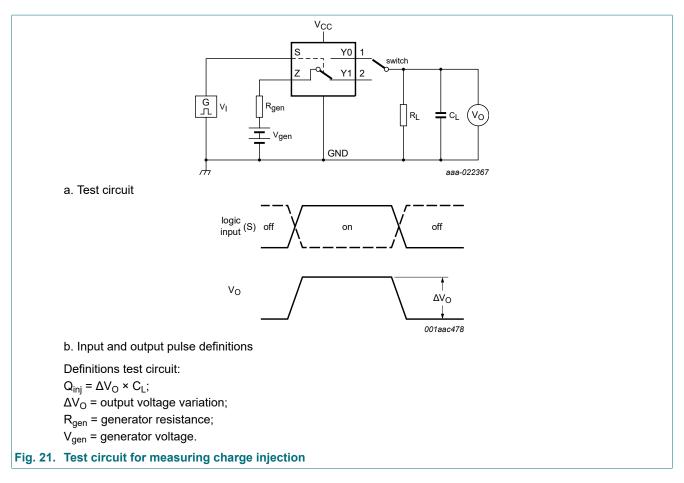






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13. Package outline

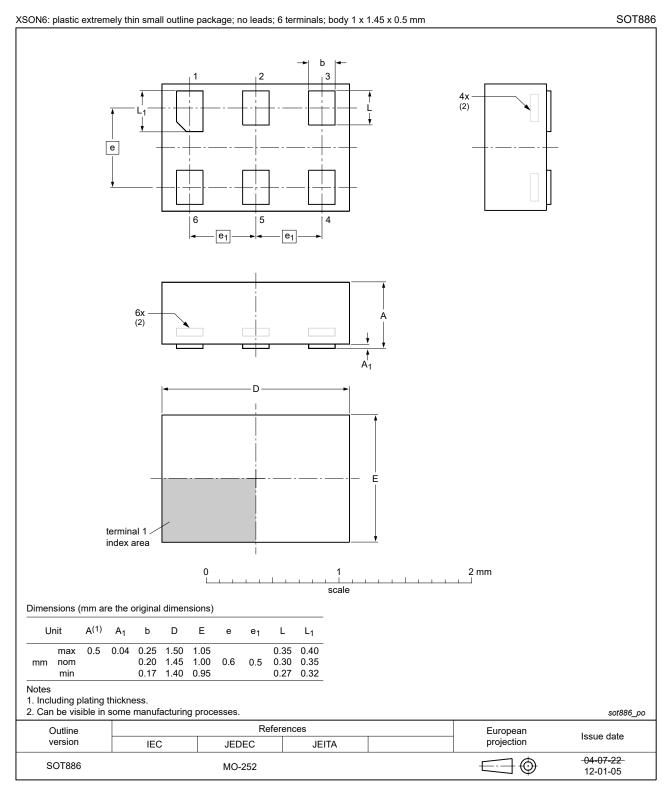


Fig. 22. Package outline SOT886 (XSON6)

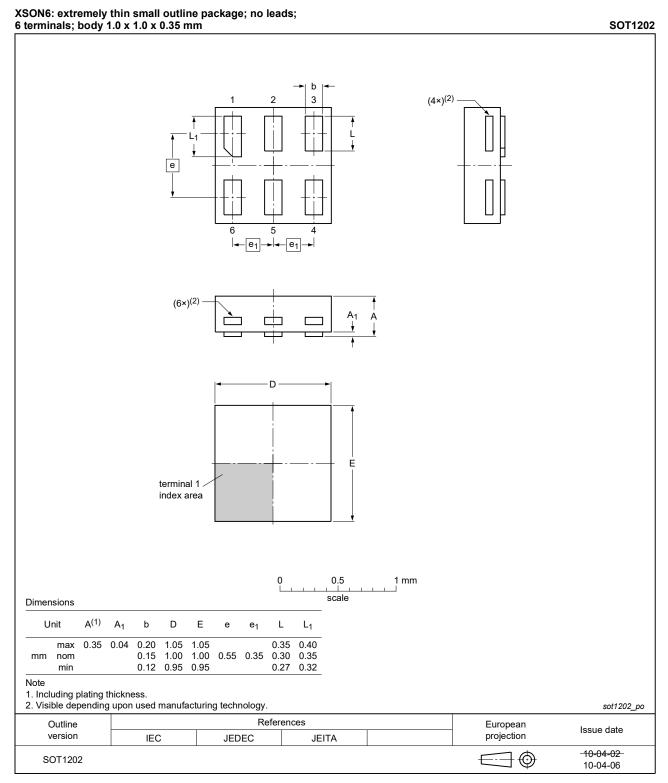


Fig. 23. Package outline SOT1202 (XSON6)

14. Abbreviations

Acronym	Description
ANSI	American National Standards Institute
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
ESDA	ElectroStatic Discharge Association
HBM	Human Body Model
JEDEC	Joint Electron Device Engineering Council

15. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
XS3A1T5157 v.1.1	20240801	Product data sheet	-	XS3A1T5157 v.1
XS3A1T5157 v.1	20200317	Product data sheet	-	-

16. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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